

TS13002HV

High Voltage NPN Transistor



TO-92



Pin Definition:

- 1. Emitter
- 2. Collector
- 3. Base

PRODUCT SUMMARY

BV _{CEO}	450V
BV _{CBO}	900V
Ic	0.8A
V _{CE(SAT)}	0.6V @ I _C =0.2A, I _B =0.04A

Features

- High Voltage
- High Speed Switching

Structure

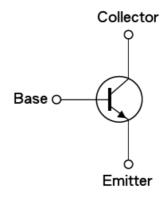
- Silicon Triple Diffused Type
- NPN Silicon Transistor

Ordering Information

Part No.	Package	Packing
TS13002HVCT B0G	TO-92	1kpcs / Bulk
TS13002HVCT A3G	TO-92	2kpcs / Ammo

Note: "G" denote for Halogen Free Product

Block Diagram



Absolute Maximum Ratings (Ta = 25°C unless otherwise noted)

Parameter		Symbol	Limit	Unit	
Collector-Base Voltage		V _{CBO}	900	V	
Collector-Emitter Voltage		V _{CEO}	450	V	
Emitter-Base Voltage		V_{EBO}	9	V	
Collector Current	DC	I _C	0.8	А	
	Pulse		1.6		
Maximum Power Dissipation @ T _C = 25°C		P _{tot}	0.8	W	
Operating Junction Temperature		T _J	+150	°C	
Operating Junction and Storage Temperature Range		T _{STG}	- 55 to +150	°C	

Thermal Performance

Parameter	Symbol	Limit	Unit
Junction to Ambient Thermal Resistance	$R\Theta_{JA}$	125	°C/W



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Electrical Specifications (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
Static						
Collector-Base Voltage	$I_C = 1 \text{mA}, I_B = 0$	BV _{CBO}	900			V
Collector-Emitter Breakdown Voltage	$I_{C} = 10 \text{mA}, I_{E} = 0$	BV _{CEO}	450			V
Emitter-Base Breakdown Voltage	$I_E = 1 \text{mA}, I_C = 0$	BV _{EBO}	9			V
Collector-Base Cutoff Current	V _{CB} =900V, I _E =0	I _{CBO}			100	μΑ
Collector-Emitter Cutoff Current	$V_{CE} = 450 \text{V}, I_{C} = 0$	I _{CEO}			100	μΑ
Emitter-Base Cutoff Current	$V_{EB} = 9V, I_{C} = 0$	I _{EBO}			100	μΑ
Collector-Emitter Saturation Voltage	I _C =0.2A, I _B =0.04A	V _{CE(SAT)}		0.2	0.6	V
Base-Emitter Saturation Voltage	I _C =0.2A, I _B =0.04A	V _{BE(SAT)}		0.9	1.5	V
	V_{CE} =5V, I_{C} =5mA		15			
DC Current Gain	V_{CE} =5V, I_{C} =100mA	h _{FE}	25		40	
	V_{CE} =5V, I_{C} =300mA		20		40	
Dynamic Characteristics						
Frequency	V _{CE} =10V, I _C =0.1A	f _T	5		-	MHz
Resistive Load Switching Time (Ratings)						
Rise Time	V _{CC} =125V, I _C =0.1A	t _r			1	μs
Storage Time	I _{B1} =I _{B2} =20mA	t _{STG}		2	5	μs
Fall Time	t _p =25μs, D=≤1%	t _f			1	μs

Note: pulse test: pulse width \leq 300µs, duty cycle \leq 2%



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Electrical Characteristics Curves (Ta = 25°C, unless otherwise noted)

Figure 1. Safe Operation Area

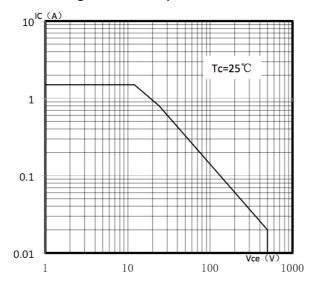


Figure 3. Vce(sat) vs. IC

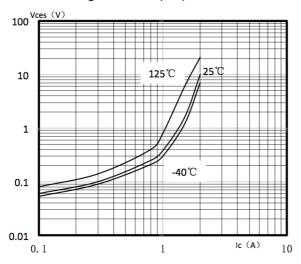


Figure 5. Power Derating

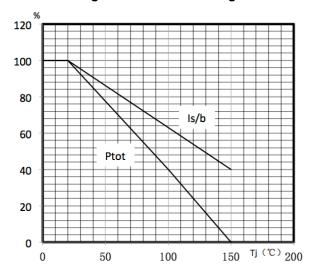


Figure 2. DC Current Gain

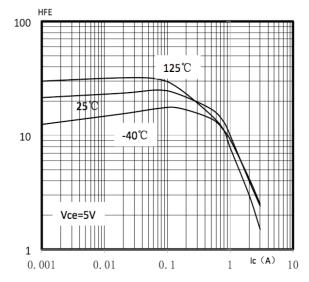
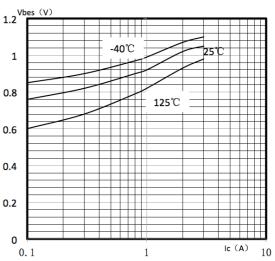


Figure 4. Vbe(sat) vs. IC



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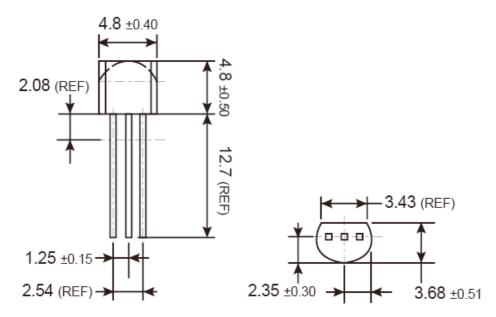
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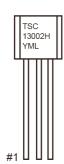
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TO-92 Mechanical Drawing



Unit: Millimeters

Marking Diagram



Y = Year Code

M = Month Code for Halogen Free Product (O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)

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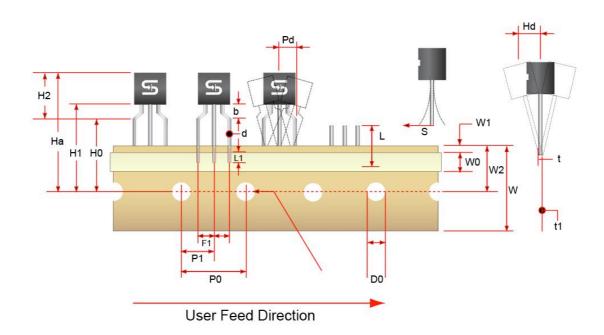
L = Lot Code

Version: A14





TO-92 Ammo Pack Mechanical Drawing



Tape Dimension

Item Description	Symbol	Dimension
Base of Package to Lead Bend	b	3.0 (typ.)
Component Height	На	23.57 (typ.)
Lead Clinch Height	H0	16.0 ±0.5
Component Base Height	H1	19.0 ±0.5
Component Top to Lead Bend	H2	8.0 (max)
Component Alignment (side / side)	Pd	1.02 (max)
Component Alignment (front / back)	Hd	0.79 (max)
Feed Hole Pitch	P0	12.7 ±0.3
Hole Center to Component Center	P1	6.25 ±0.4
Lead Spread	F1	2.5 ±0.3
Lead Thickness	d	0.46 (typ.)
Cut Lead Length	L	10.9 (max)
Taped Lead Length	L1	5.31 (typ.)
Taped Lead Thickness	t	0.81 ±0.2
Carrier Tape Thickness	t1	0.5 ±0.2
Carrier Tape Width	W	18.0 ±0.5
Hold – down Tape Width	W0	0.5 ±0.2
Hold – down Tape position	W1	9.0 ±0.7
Feed Hole Position	W2	6.0 ±0.2
Sprocket Hole Diameter	D0	4.0 ±0.2
Lead Spring Out	S	0.1 (max)

Note: All dimensions are in millimeter.



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